Erratum: Auger recombination in low-band-gap $n$-type InGaAs

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In the original article, on the last page, we state that “To compare our results to the literature, we used the expression $\tau = \frac{1}{Cn^2}$, and found the Auger coefficient for passivated 0.74, 0.60, and 0.50 eV $n$-InGaAs to be 1.8, 1.2, and $0.7 \times 10^{-28}$ cm$^2$/s, respectively.” The order was reversed, and the sentence should read “To compare our results to the literature, we used the expression, $\tau = \frac{1}{Cn^2}$, and found the Auger coefficient for passivated 0.74, 0.60, and 0.50 eV $n$-InGaAs to be 0.7, 1.2, and $1.8 \times 10^{-28}$ cm$^2$/s, respectively.”